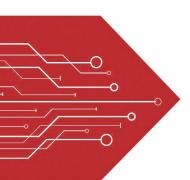
# MSKSEMI















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# **VOLTAGE RANGE** 20 to 100 Volts **CURRENT** 5.0 Ampere







# **FEATURES**

- \* Ideal for surface mount applications
- \* Easy pick and place
- \* Built-in strain relief
- \* Low forward voltage drop

## **MECHANICAL DATA**

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Metallurgically bonded construction
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 0.21 grams

# MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

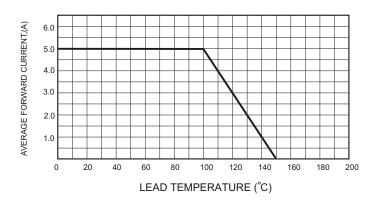
P/N(MARK)		SK52C	SK53C	SK54C	SK55C	SK56C	SK58C	SK59C	SK510C	UNITS
Maximum Recurrent Peak Reverse Voltage		20	30	40	50	60	80	90	100	V
Maximum RMS Voltage		14	21	28	35	42	56	63	70	V
Maximum DC Blocking Voltage		20	30	40	50	60	80	90	100	V
Maximum Average Forward Rectified Current				•				•		
at T∟=90 ℃			5.0						Α	
Peak Forward Surge Current, 8.3 ms single half sine-wave										
superimposed on rated load (JEDEC method)			150						Α	
Maximum Instantaneous Forward Voltage at 5.0A			0.55 0.70		0.85			V		
Maximum DC Reverse Current	Ta=25°C	0.1 0.02			mA					
at Rated DC Blocking Voltage	Ta=100°C	5 2			mA					
Typical Junction Capacitance (Note1)		300						pF		
Typical Thermal Resistance R JL (Note 2)		10						°C/W		
Operating Temperature Range T <sub>J</sub>			-65 —+150						°C	
Storage Temperature Range Tsтg		-65 — +150					°C			

- 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
- 2. Thermal Resistance Junction to Lead.



## RATING AND CHARACTERISTIC CURVES (SK52C THRU SK510C)

### FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE



#### FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

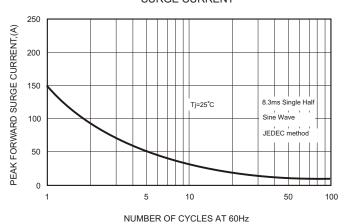
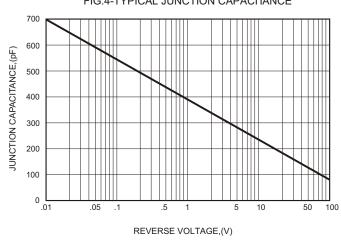


FIG.4-TYPICAL JUNCTION CAPACITANCE



### FIG.2-TYPICAL FORWARD

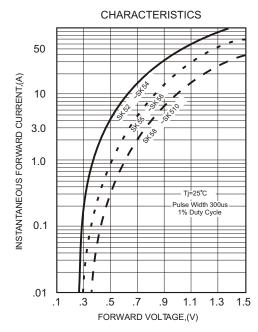
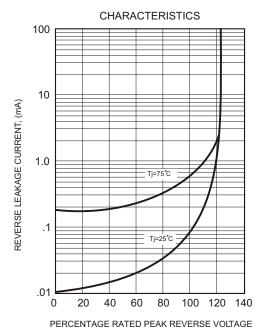
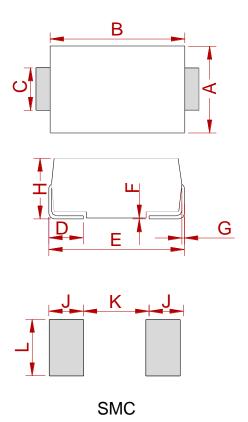


FIG.5 - TYPICAL REVERSE



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# **PACKAGE MECHANICAL DATA**



	Dimensions					
Ref.	Millimeters		Inches			
	Min.	Max.	Min.	Max.		
Α	5.75	6.25	0.226	0.246		
В	6.90	7.40	0.272	0.291		
С	2.75	3.25	0.108	0.128		
D	0.95	1.52	0.037	0.060		
E	7.70	8.20	0.303	0.323		
F	0.051	0.203	0.002	0.008		
G	0.15	0.31	0.006	0.012		
Н	2.15	2.62	0.085	0.103		
J	2.40		0.094			
K		4.20		0.165		
L	3.30		0.130			

# **REEL SPECIFICATION**

P/N	PKG	QTY
SK52C THRU SK510C	SMC	3000



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